

产品规格书

Specifcation of products

产品名称:快速单相桥

产品型号: MFQ180U3NH5

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

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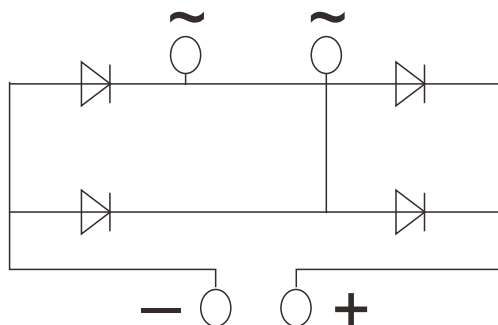
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拟制	审核	核准
蓝少波	陈一凡	曹剑龙

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _O	DC output current	Single-phase full wave rectifying circuit, T _C =100°C	125		180		A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms	125		300		V
I _{RRM}	Repetitive peak current	at V _{RRM}	125			5	mA
I _{FSM}	Surge forward current	10ms half sine wave	125		1.8		KA
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}			10.9		A ² s*10 ³
V _{FO}	Threshold voltage		125			0.75	V
V _{FM}	Peak forward voltage	I _{FM} =180A	25			1.20	V
t _{rr}	Reverse Recove ry Tei m	I _F =1A, V _R =30V, di _F /dt=-200A/μs				50	ns
R _{th(j-c)}	Thermal resistance Junction to heatsink	Single side cooled				0.150	°C /W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(max)		2500			V
F _m	Terminal connection torque(M6)				5.0		N.m
	Mounting torque(M6)				5.0		N.m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight						g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

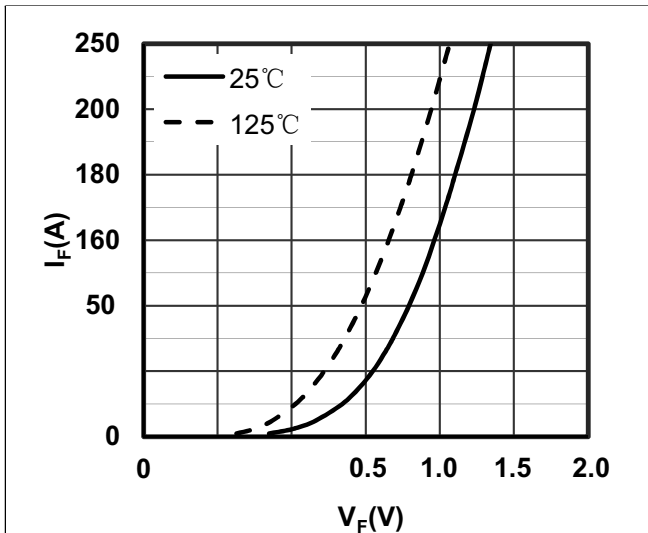


Fig1. Forward Characteristics

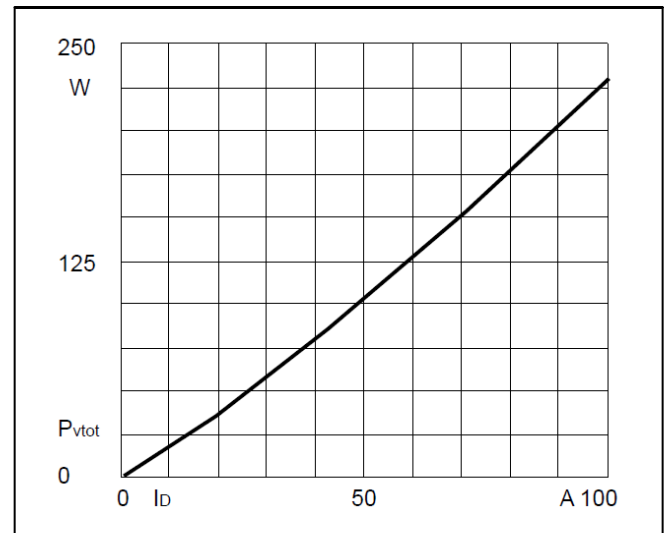


Fig2. Power dissipation

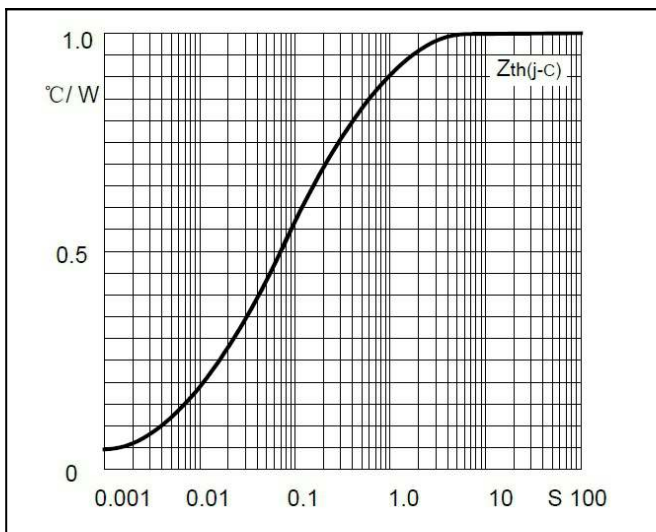


Fig3. Transient thermal impedance

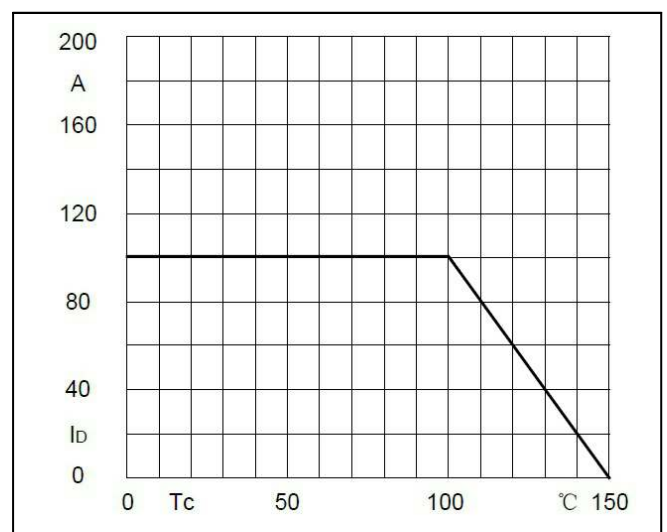
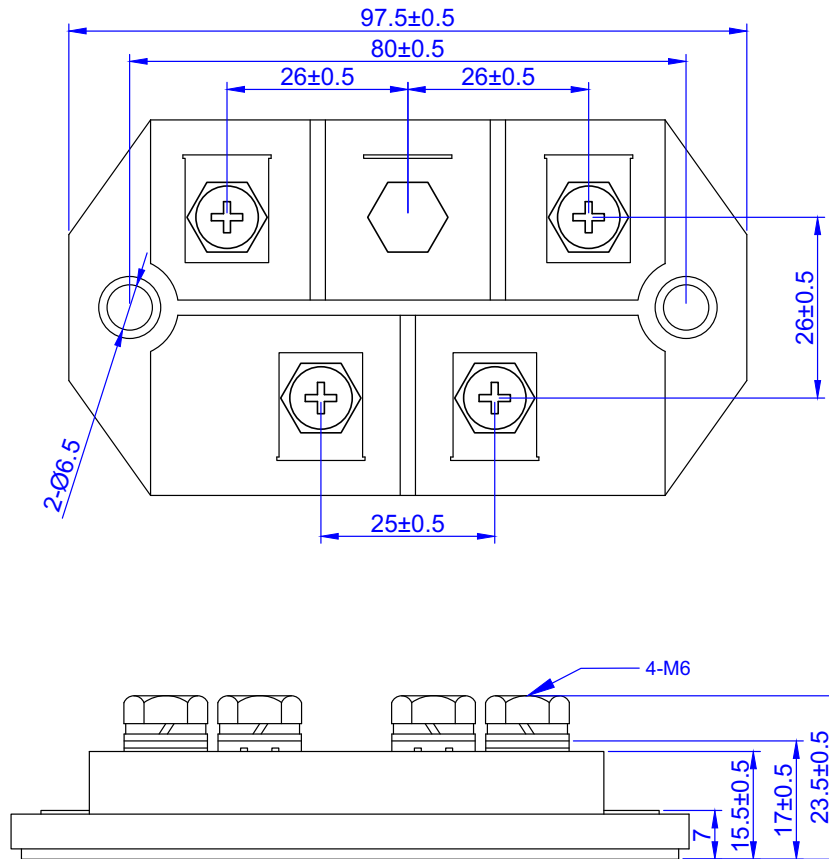


Fig4. Forward Current Derating Curve

Package Outline Information



Unit:mm